

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

IPB090N06N3

FEATURES

- With TO-263(D2PAK) packaging
- · Ultra-fast body diode
- High speed switching
- Very low on-resistance
- · Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operationz

APPLICATIONS

Switching applications

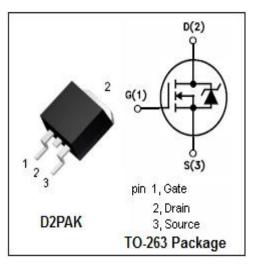
SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage 60		V	
V _{GSS}	Gate-Source Voltage ±20		V	
ID	Drain Current-Continuous	50	А	
I _{DM}	Drain Current-Single Pulsed	200	А	
PD	Total Dissipation	71	W	
Tj	Operating Junction Temperature	-55~175	°C	
T _{stg}	Storage Temperature	-55~175	°C	

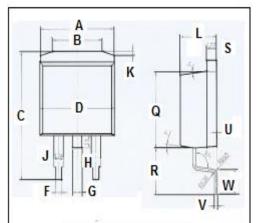
ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

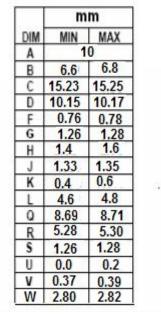
• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	1.6	°C /W	
Rth(ch-a)	Channel-to-ambient thermal resistance		°C /W	

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isc website: www.iscsemi.cn

isc & iscsemi is registered trademark



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ELECTRICAL CHARACTERISTICS

$T_{C}\text{=}25^{\circ}\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 1mA	60			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} =±20V; I _D =0.034mA	2		4	v
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =50A		7.7	9.0	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} =0V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 60V; V _{GS} = 0V;@Tj=25℃ Tj=125℃			1 100	μA
V _{SDF}	Diode forward voltage	I _{SD} =50A, V _{GS} = 0 V			1.2	V

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